

Product Summary

| $V_{(BR)DSS}$ | $R_{DS(on)MAX}$ | I_D |
|---------------|--------------------|-------|
| 30V | 12m Ω @10V | 10A |
| | 16m Ω @4.5V | |

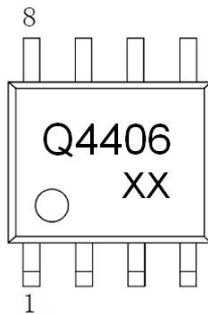
Feature

- High cell density trench N-ch MOSFETs
- Super low gate charge
- Advanced high cell density Trench technology

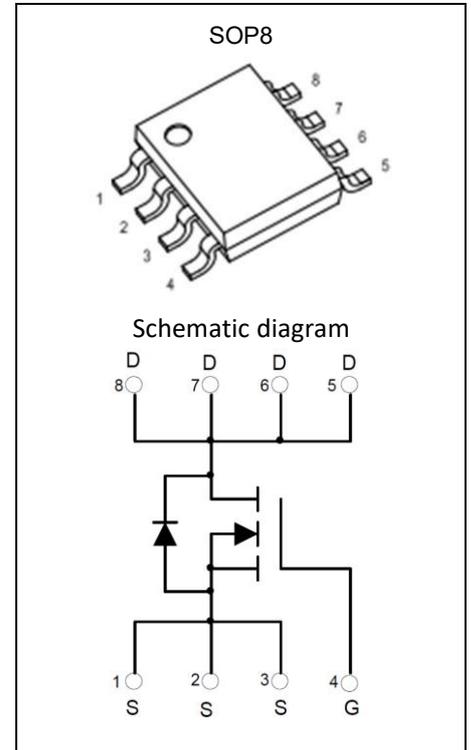
Application

- Battery protection applications
- Load switch

MARKING:



Q4406= Device code
 Solid dot=Pin1 indicator
 Solid dot = Green molding compound device,
 if none, the normal device
 YY=Date Code



ABSOLUTE MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|---|-----------------|----------|---------------------------|
| Drain-Source Voltage | V_{DS} | 30 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current | I_D | 10 | A |
| Pulsed Drain Current | I_{DM} | 40 | A |
| Single Pulse Avalanche Energy | $E_{AS}^{(1)}$ | 100 | mJ |
| Power Dissipation | P_D | 1.4 | W |
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}$ | 89 | $^\circ\text{C}/\text{W}$ |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{STG} | -55~+150 | $^\circ\text{C}$ |

(1). E_{AS} condition: $V_{DD}=-50\text{V}$, $L=0.5\text{mH}$, $R_G=25\Omega$, Starting $T_J = 25^\circ\text{C}$

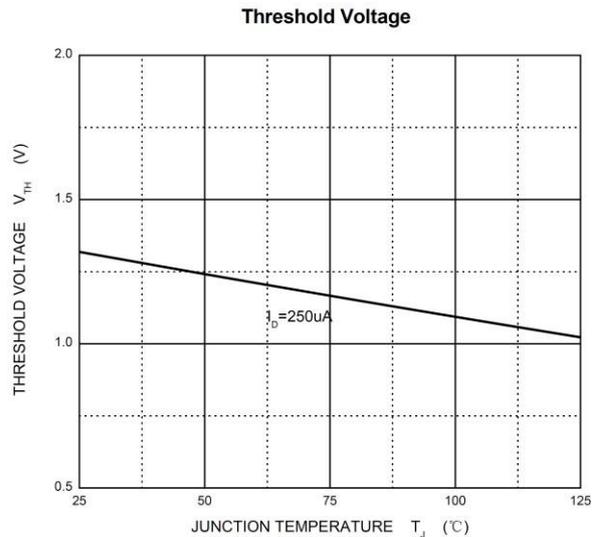
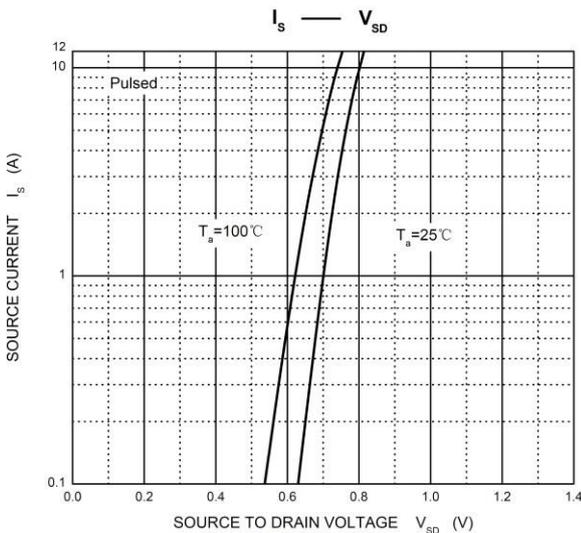
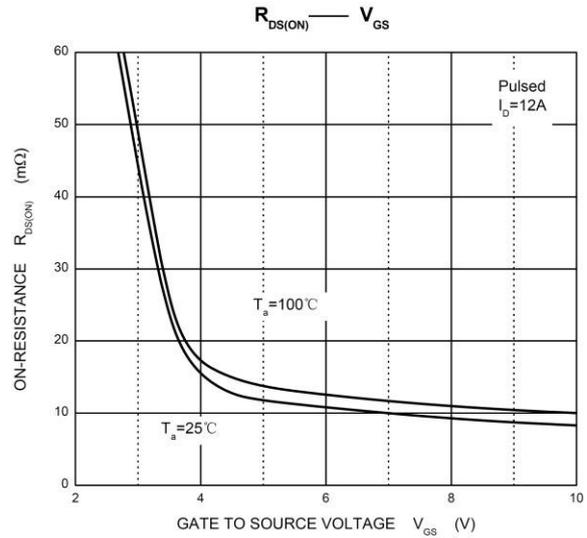
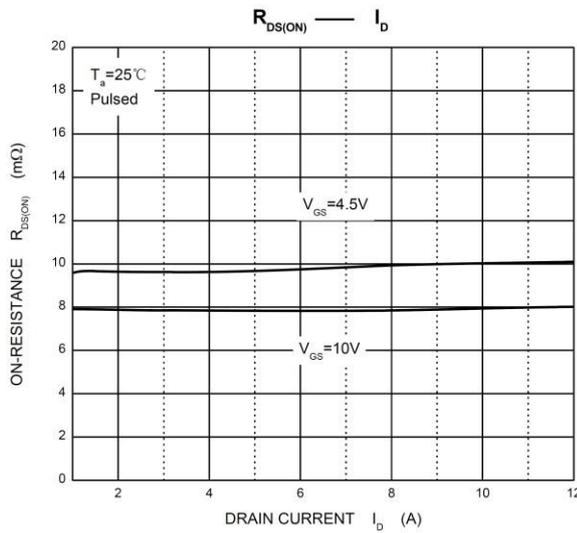
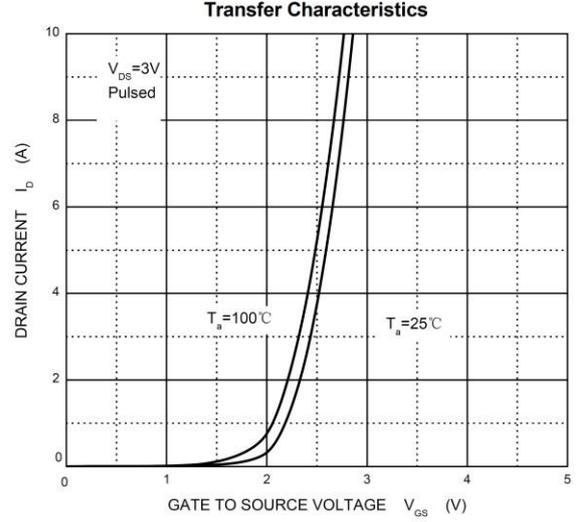
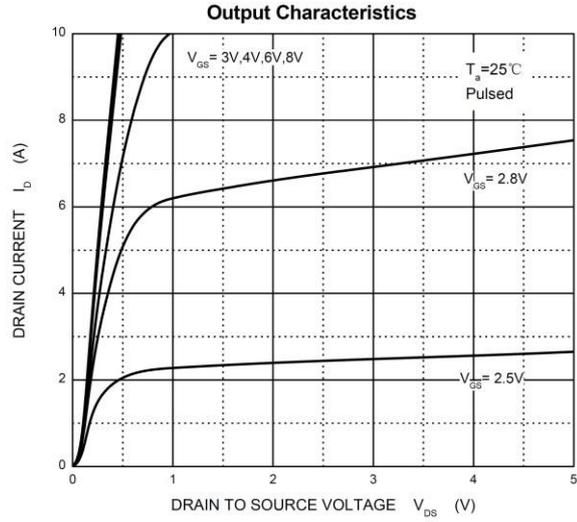
MOSFET ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Test Condition | Min | Type | Max | Unit |
|--|---------------|---|-----|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-source breakdown voltage | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$ | 30 | | | V |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = 30V, V_{GS} = 0V$ | | | -1 | μA |
| Gate-body leakage current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | | | ± 100 | nA |
| Gate threshold voltage ¹ | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 1.0 | 1.35 | 3.0 | V |
| Drain-source on-resistance ¹ | $R_{DS(on)}$ | $V_{GS} = 10V, I_D = 12A$ | | 8 | 12 | m Ω |
| | | $V_{GS} = 4.5V, I_D = 10A$ | | 10 | 16 | |
| Forward transconductance ¹ | g_{FS} | $V_{DS} = 5V, I_D = 10A$ | 10 | 14 | | S |
| Dynamic characteristics² | | | | | | |
| Input capacitance | C_{iss} | $V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$ | | 1570 | | pF |
| Output capacitance | C_{oss} | | | 320 | | |
| Reverse transfer capacitance | C_{rss} | | | 190 | | |
| Switching Characteristics² | | | | | | |
| Total gate charge | Q_g | $V_{DS} = 15V, V_{GS} = 5V, I_D = 10A$ | | 13.5 | | nC |
| Gate-source charge | Q_{gs} | | | 5.6 | | |
| Gate-drain charge | Q_{gd} | | | 3.7 | | |
| Turn-on delay time | $t_{d(on)}$ | $V_{DD} = 25V, V_{GS} = 10V, R_G = 63\Omega, R_L = 6.7\Omega, I_D = 1A$ | | 31 | | ns |
| Turn-on rise time | t_r | | | 22 | | |
| Turn-off delay time | $t_{d(off)}$ | | | 105 | | |
| Turn-off fall time | t_f | | | 82 | | |
| Diode Characteristics | | | | | | |
| Continuous Source Current | I_S | $V_G = V_D = 0V, \text{ Force Current}$ | | | 10 | A |
| Pulsed Source Current | I_{SM} | | | | 40 | |
| Diode Forward Voltage ¹ | V_{SD} | $V_{GS} = 0V, I_S = 10A, T_J = 25^\circ\text{C}$ | | 0.8 | 1.2 | V |

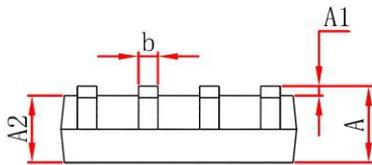
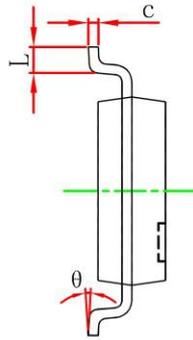
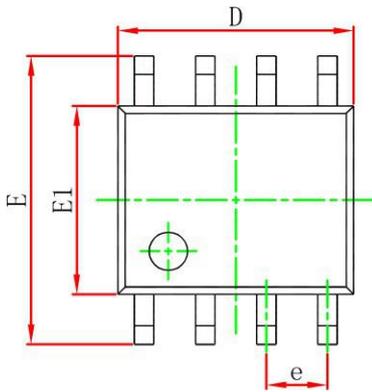
Notes:

1. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
2. Guaranteed by design, not subject to production testing.

Typical Electrical and Thermal Characteristics



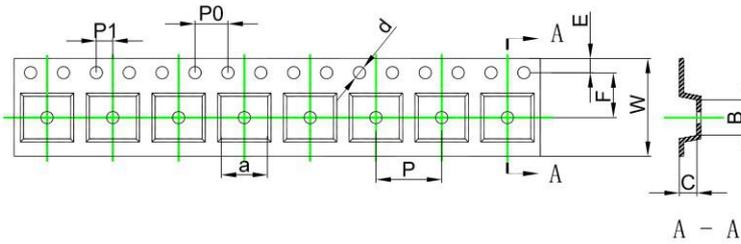
SOP8 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.007 | 0.010 |
| D | 4.800 | 5.000 | 0.189 | 0.197 |
| e | 1.270 (BSC) | | 0.050 (BSC) | |
| E | 5.800 | 6.200 | 0.228 | 0.244 |
| E1 | 3.800 | 4.000 | 0.150 | 0.157 |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

SOP8 Tape and Reel

SOP8 Embossed Carrier Tape



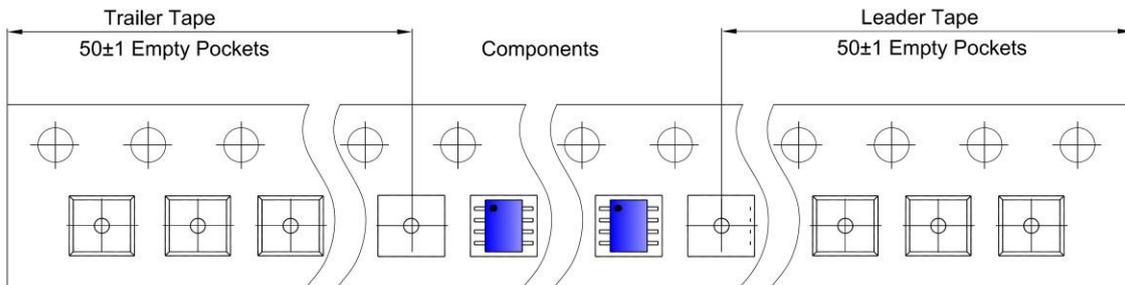
Packaging Description:

SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 2,500 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

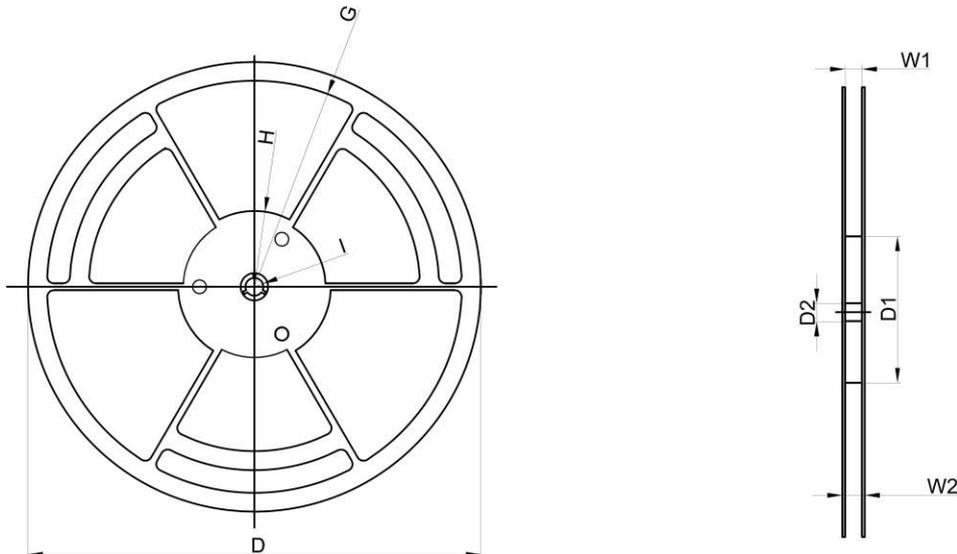
ALL DIM IN mm

| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|------|------|------|-------|------|------|------|------|------|-------|
| Pkg type | a | B | C | d | E | F | P0 | P | P1 | W |
| SOP8 | 6.40 | 5.40 | 2.10 | Ø1.50 | 1.75 | 5.50 | 4.00 | 8.00 | 2.00 | 12.00 |

SOP8 Tape Leader and Trailer



SOP8 Reel



| Dimensions are in millimeter | | | | | | | | |
|------------------------------|---------|--------|-------|---------|--------|-------|-------|-------|
| Reel Option | D | D1 | D2 | G | H | I | W1 | W2 |
| 13" Dia | Ø330.00 | 100.00 | 13.00 | R151.00 | R56.00 | R6.50 | 12.40 | 17.60 |

| REEL | Reel Size | Box | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|-----------|-----------|-----------|--------------|------------|-----------------|----------|
| 4,000 pcs | 13 inch | 8,000 pcs | 360×360×65 | 64,000 pcs | 565×380×390 | |